



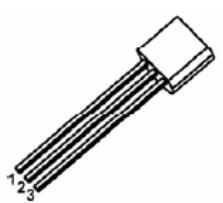
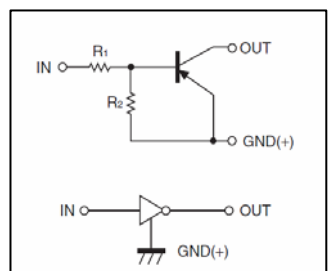
Digital Transistors (Built-in Resistors)

DTA113ZVA DIGITAL TRANSISTOR (PNP)

FEATURE

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input.They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

PIN CONNENCTIONS and EQUIVALENT CIRCUIT

<p>DTA113ZVA</p> 	<p>TO-92</p> <ol style="list-style-type: none"> 1. GND 2. OUT 3. IN 	<p>Equivalent Circuit</p> 
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MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _{CC}	Supply Voltage	-50	V
V _{IN}	Input Voltage	-10~+5	V
I _O	Output Current	-100	mA
P _D	Power Dissipation	625	mW
T _J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =-5V, I _O =-100μA	-0.3			V
	V _{I(on)}	V _O =-0.3V, I _O =-20mA			-3	V
Output voltage	V _{O(on)}	I _O /I _I =-10mA/-0.5mA			-0.3	V
Input current	I _I	V _I =-5V			-7.2	mA
Output current	I _{O(off)}	V _{CC} =-50V, V _I =0			-0.5	μA
DC current gain	G _I	V _O =-5V, I _O =-5mA	33			
Input resistance	R ₁		0.7	1	1.3	kΩ
Resistance ratio	R ₂ /R ₁		8	10	12	
Transition frequency	f _T	V _O =-10V, I _O =-5mA, f=100MHz		250		MHz

Typical Characteristics

DTA113ZVA

